NSN 5962-01-366-0265

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View Online at https://aerobasegroup.com/nsn/5962-01-366-0265

Body Length: 2.435 inches **Body Width:** Between 0.510 inches and 0.620 inches **Body Height:** 0.210 inches **Maximum Power Dissipation Rating:** 1.5 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and bidirectional and high impedance and w/enable and w/disable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 41 input **Case Outline Source And Designator:** D-14 mil-m-38510 **Current Rating Per Characteristic:** 230.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Product Name:** Dual port sram (master) **Voltage Rating And Type Per Characteristic:** -0.5 volts power source and 7.0 volts power source **Capitance Rating Per Characteristic:** 12.00 input picofarads and 10.00 output picofarads **Time Rating Per Chacteristic:** 45.00 nanoseconds access **Memory Device Type:** Ram **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:**

48 printed circuit

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N/a

Unit Of Measure:

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Demilitarization:

No

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